

# Si APD

S8890 series

## Long wavelength type APD

### Features

- High sensitivity
- High gain
- Low terminal capacitance

### Applications

- YAG laser detection
- Long wavelength light detection

### Structure / Absolute maximum ratings

| Type no. | Dimensional outline/Window material*1 | Package | Effective photosensitive area size*2<br>(mm) | Effective photosensitive area<br>(mm <sup>2</sup> ) | Absolute maximum ratings        |                               |
|----------|---------------------------------------|---------|--|---|---------------------------------|-------------------------------|
|          |                                       |         |  |   | Operating temperature Topr (°C) | Storage temperature Tstg (°C) |
| S8890-02 | (1)/K                                 | TO-5    | φ0.2   | 0.03  | -20 to +85                      | -55 to +125                   |
| S8890-05 |                                       |         | φ0.5   | 0.19  |                                 |                               |
| S8890-10 |                                       |         | φ1.0   | 0.78  |                                 |                               |
| S8890-15 |                                       |         | φ1.5   | 1.77  |                                 |                               |
| S8890-30 | (2)/K                                 | TO-8    | φ3.0   | 7.0   |                                 |                               |

Note: Exceeding the absolute maximum ratings even momentarily may cause a drop in product quality. Always be sure to use the product within the absolute maximum ratings.

\*1: K=borosilicate glass

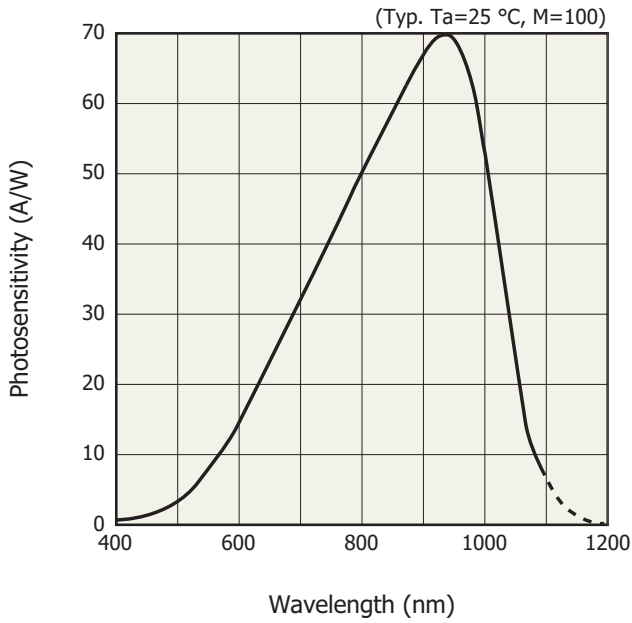
\*2: Area in which a typical gain can be obtained

### Electrical and optical characteristics (Typ. Ta=25 °C, unless otherwise noted)

| Type no. | Spectral response range λ<br>(nm) | Peak*3 sensitivity wavelength λp<br>(nm) | Breakdown voltage VBR<br>ID=100 μA |          | Temp. coefficient of VBR<br>(V/°C) | Dark*3 current ID |           | Terminal*3 capacitance Ct<br>(pF) | Cutoff*3 frequency fc<br>RL=50 Ω<br>(MHz) | Excess*3 noise figure x λ=800 nm | Gain M<br>λ=800 nm |
|----------|-----------------------------------|--|------------------------------------|----------|------------------------------------|-------------------|-----------|-----------------------------------|---|----------------------------------|--------------------|
|          |                                   |  | Typ. (V)                           | Max. (V) |                                    | Typ. (nA)         | Max. (nA) |                                   |   |                                  |                    |
| S8890-02 | 400 to 1100                       | 940                                      | 500                                | 800      | 3.5                                | 0.2               | 2         | 0.2                               | 280                                       | 0.3                              | 100                |
| S8890-05 |                                   |  |                                    |          |                                    | 1.5               | 15        | 0.5                               | 240                                       |                                  |                    |
| S8890-10 |                                   |  |                                    |          |                                    | 5.0               | 50        | 1.5                               | 230                                       |                                  |                    |
| S8890-15 |                                   |  |                                    |          |                                    | 10.0              | 100       | 2.5                               | 220                                       |                                  |                    |
| S8890-30 |                                   |  |                                    |          |                                    | 15.0              | 150       | 8.0                               | 220                                       |                                  |                    |

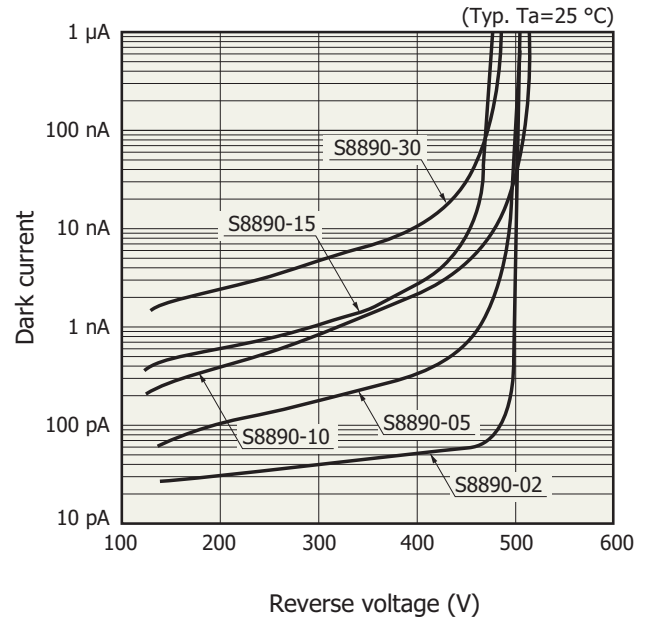
\*3: Values measured at a gain listed in the characteristics table

**Spectral response**



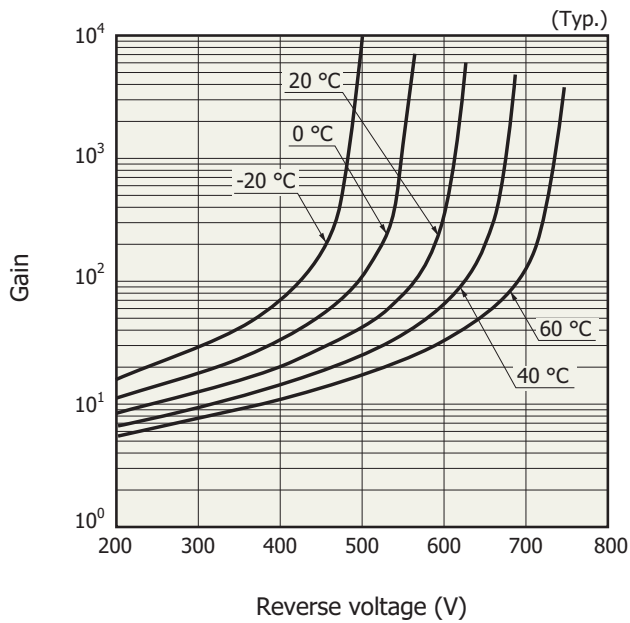
KAPDB0064EB

**Dark current vs. reverse voltage**



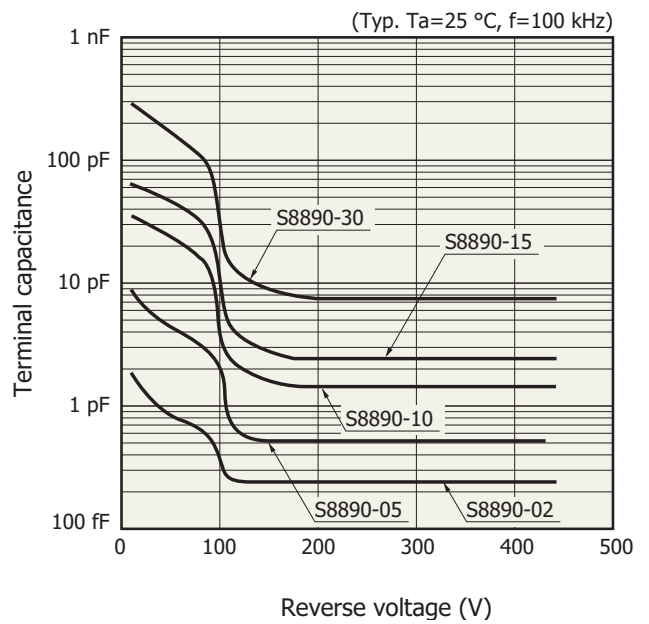
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**Gain vs. reverse voltage**



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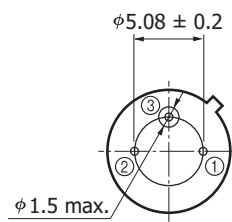
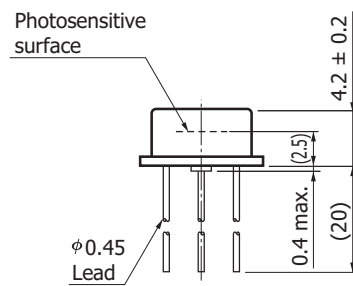
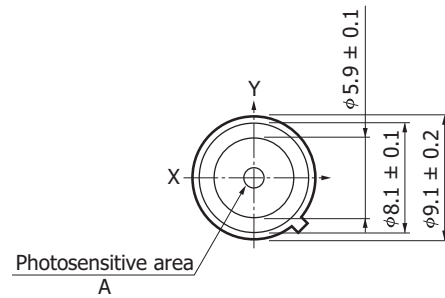
**Terminal capacitance vs. reverse voltage**



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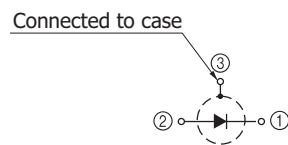
### Dimensional outlines (unit: mm)

(1) S8890-02/-05/-10/-15



Distance from photosensitive area center to cap center  
 $-0.3 \leq X \leq +0.3$   
 $-0.3 \leq Y \leq +0.3$

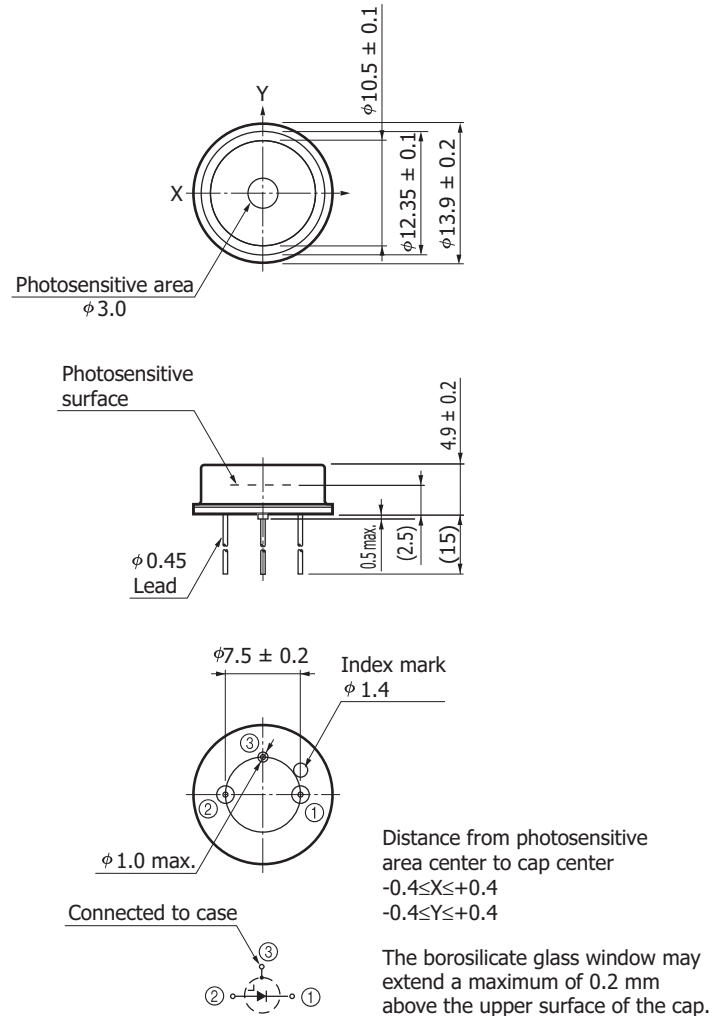
The borosilicate glass window may extend a maximum of 0.2 mm above the upper surface of the cap.



| Type no. | A    |
|----------|------|
| S8890-02 | φ0.2 |
| S8890-05 | φ0.5 |
| S8890-10 | φ1.0 |
| S8890-15 | φ1.5 |

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(2) S8890-30



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Information described in this material is current as of September, 2012.

Product specifications are subject to change without prior notice due to improvements or other reasons. Before assembly into final products, please contact us for the delivery specification sheet to check the latest information.

The product warranty is valid for one year after delivery and is limited to product repair or replacement for defects discovered and reported to us within that one year period. However, even if within the warranty period we accept absolutely no liability for any loss caused by natural disasters or improper product use.

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# HAMAMATSU

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